

NCE Automotive N-Channel Super Trench Power MOSFET

Description

The NCEAP4040Q uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(on)}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

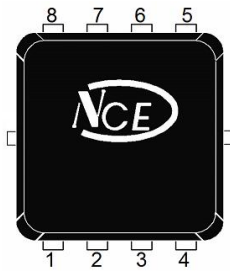
Application

- Automotive application
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

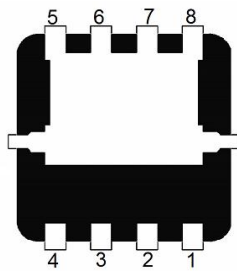
General Features

- $V_{DS} = 40V, I_D = 42A$
 $R_{DS(on)} = 7.5m\Omega$ (typical) @ $V_{GS} = 10V$
 $R_{DS(on)} = 9.8m\Omega$ (typical) @ $V_{GS} = 4.5V$
- Excellent gate charge x $R_{DS(on)}$ product(FOM)
- Very low on-resistance $R_{DS(on)}$
- 175°C operating temperature
- Pb-free lead plating; RoHS compliant
- Halogen-free according to IEC61249-2-21
- 100% UIS tested
- 100% ΔV_{ds} tested
- **AEC-Q101 qualified**

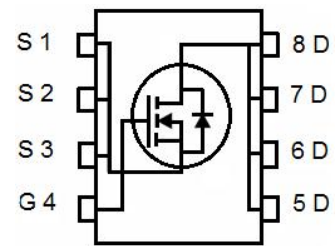
PDFN 3.3X3.3-8L



Top View



Bottom View



Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP4040Q	NCEAP4040Q	PDFN3.3X3.3-8L	-	-	-

Absolute Maximum Ratings ($T_c = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	40	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous	I_D	42	A
Drain Current-Continuous($T_c = 100^\circ C$)	$I_D(100^\circ C)$	30	A
Pulsed Drain Current	I_{DM}	168	A
Maximum Power Dissipation	P_D	30	W
Derating factor		0.2	W/°C
Single pulse avalanche energy (Note 1)	E_{AS}	115	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 175	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	5	$^{\circ}\text{C/W}$
Thermal Resistance, Junction-to-Ambient (Note 4)	$R_{\theta JA}$	60	$^{\circ}\text{C/W}$

Electrical Characteristics ($T_C=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	40	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V, V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	1.0	1.5	2.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =20A	-	7.5	8.8	mΩ
		V _{GS} =4.5V, I _D =20A	-	9.8	13	mΩ
Forward Transconductance	g _{FS}	V _{DS} =5V, I _D =20A	-	30	-	S
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =20V, V _{GS} =0V, F=1.0MHz	-	831	-	pF
Output Capacitance	C _{oss}		-	318	-	pF
Reverse Transfer Capacitance	C _{rss}		-	24	-	pF
Switching Characteristics <small>(Note 2)</small>						
Turn-on Delay Time	t _{d(on)}	V _{DD} =20V, I _D =20A V _{GS} =10V, R _G =1.6Ω	-	6	-	nS
Turn-on Rise Time	t _r		-	2.8	-	nS
Turn-Off Delay Time	t _{d(off)}		-	23	-	nS
Turn-Off Fall Time	t _f		-	3	-	nS
Total Gate Charge	Q _g	V _{DS} =20V, I _D =20A, V _{GS} =10V	-	17.6	-	nC
Gate-Source Charge	Q _{gs}		-	3.5	-	nC
Gate-Drain Charge	Q _{gd}		-	3.1	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =20A	-	-	1.2	V
Diode Forward Current	I _S		-	-	42	A
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F = I _S	-	11	-	nS
Reverse Recovery Charge	Q _{rr}	di/dt = 100A/μs	-	19	-	nC

Notes:

1. EAS condition : $T_J=25^{\circ}\text{C}, V_{DD}=20V, V_G=10V, L=0.5\text{mH}, R_G=25\Omega$
2. Guaranteed by design, not subject to production
3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of $T_{J(MAX)}=175^{\circ}\text{C}$. The SOA curve provides a single pulse rating.
4. The value of $R_{\theta JA}$ is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with $T_A=25^{\circ}\text{C}$. The value in any given application depends on the user's specific board design, and the maximum temperature of 175°C may be used if the PCB allows it.

Typical Electrical and Thermal Characteristics

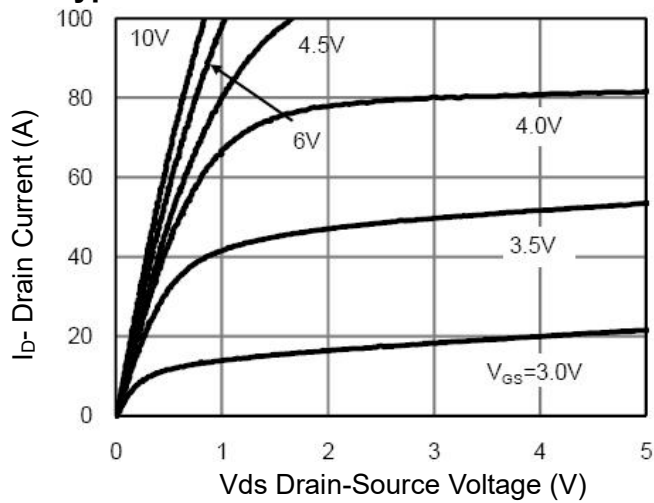


Figure 1 Output Characteristics

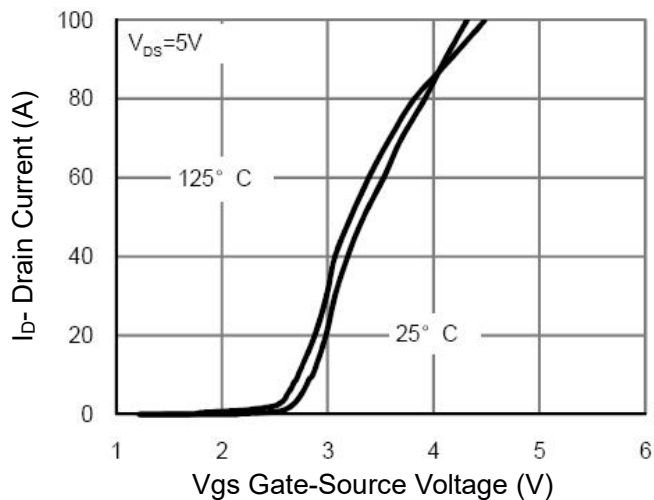


Figure 2 Transfer Characteristics

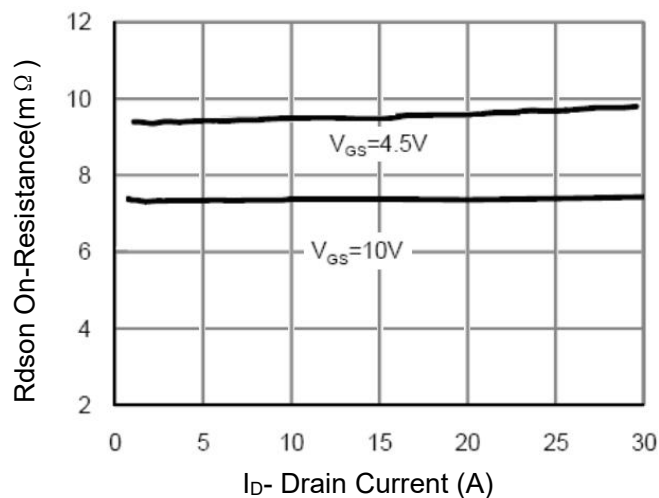


Figure 3 Rdson- Drain Current

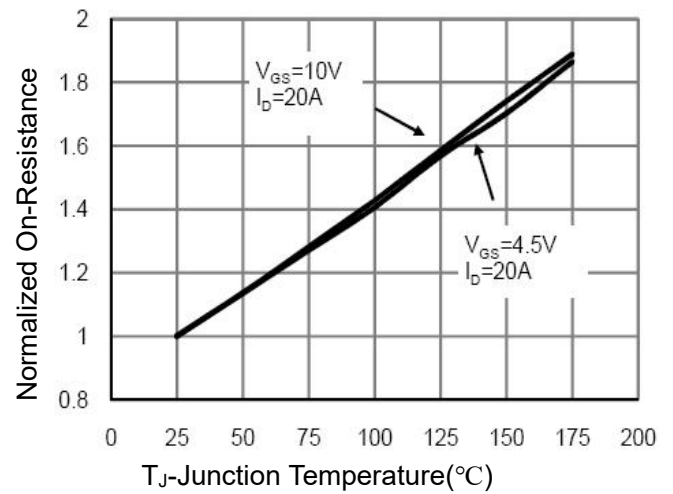


Figure 4 Rdson-Junction Temperature

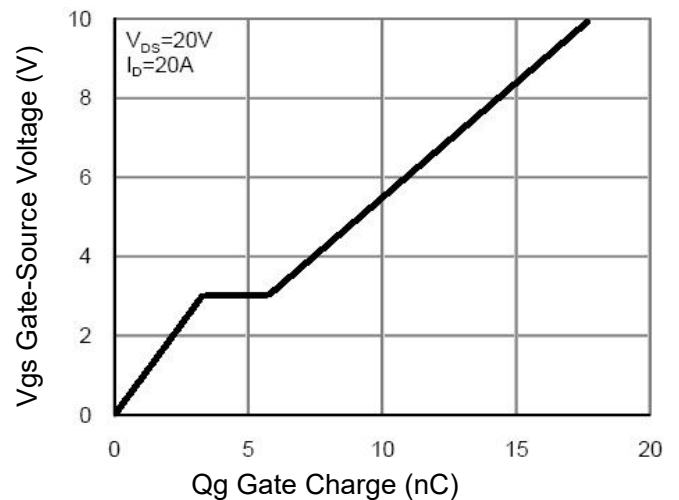


Figure 5 Gate Charge

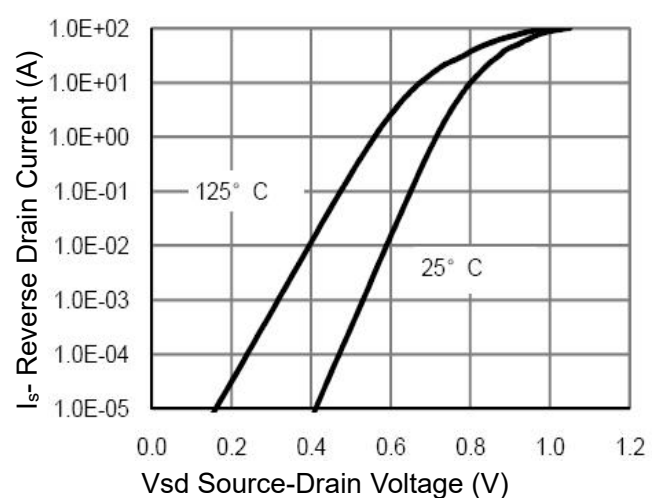


Figure 6 Source- Drain Diode Forward

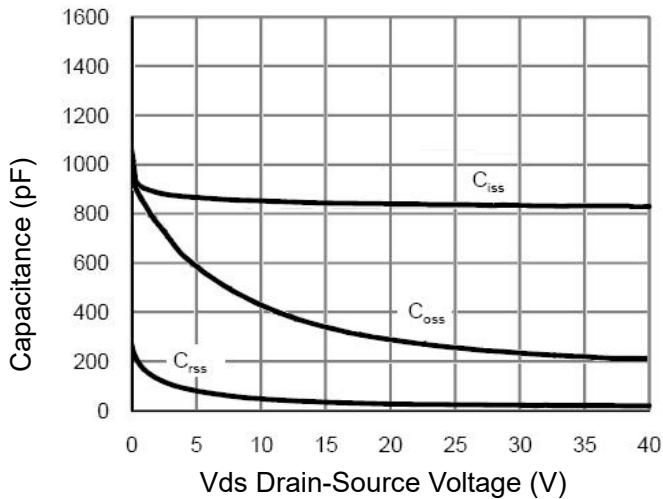


Figure 7 Capacitance vs Vds

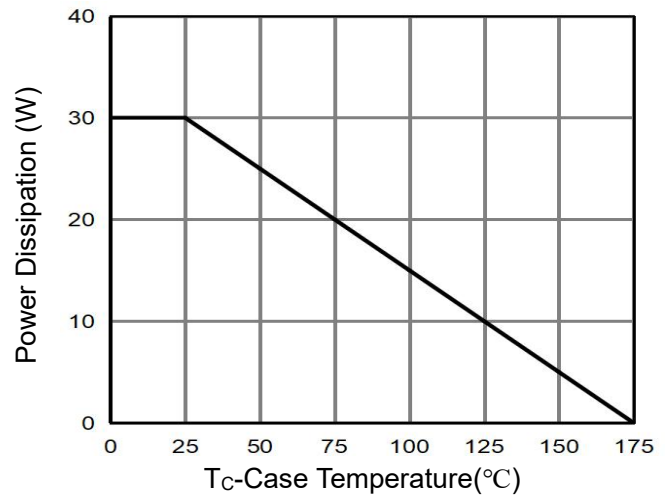


Figure 9 Power De-rating

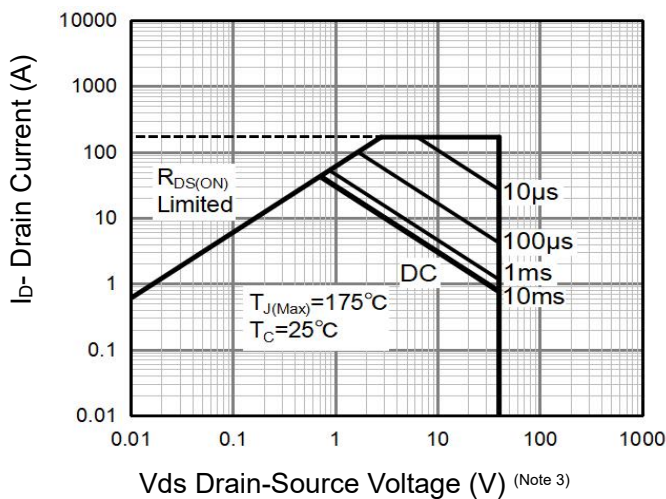


Figure 8 Safe Operation Area

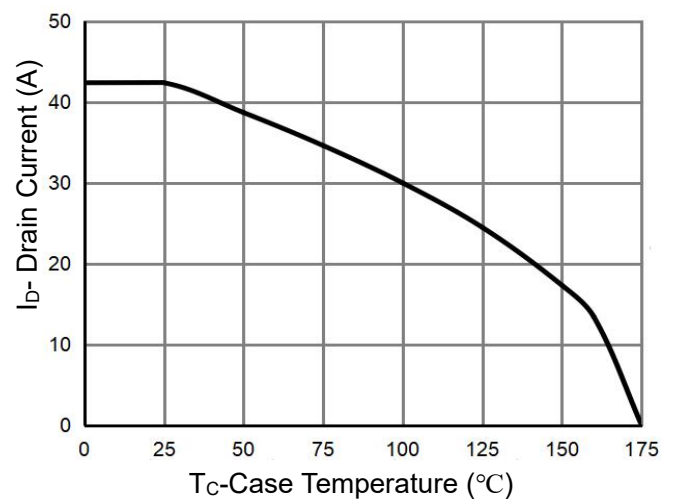


Figure 10 Current De-rating

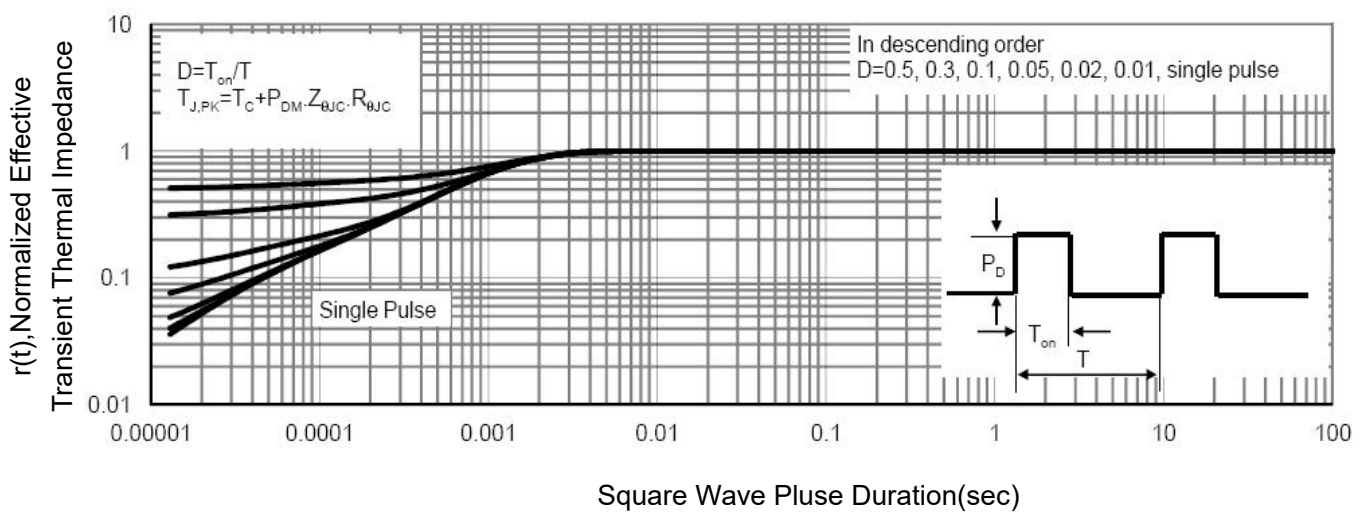
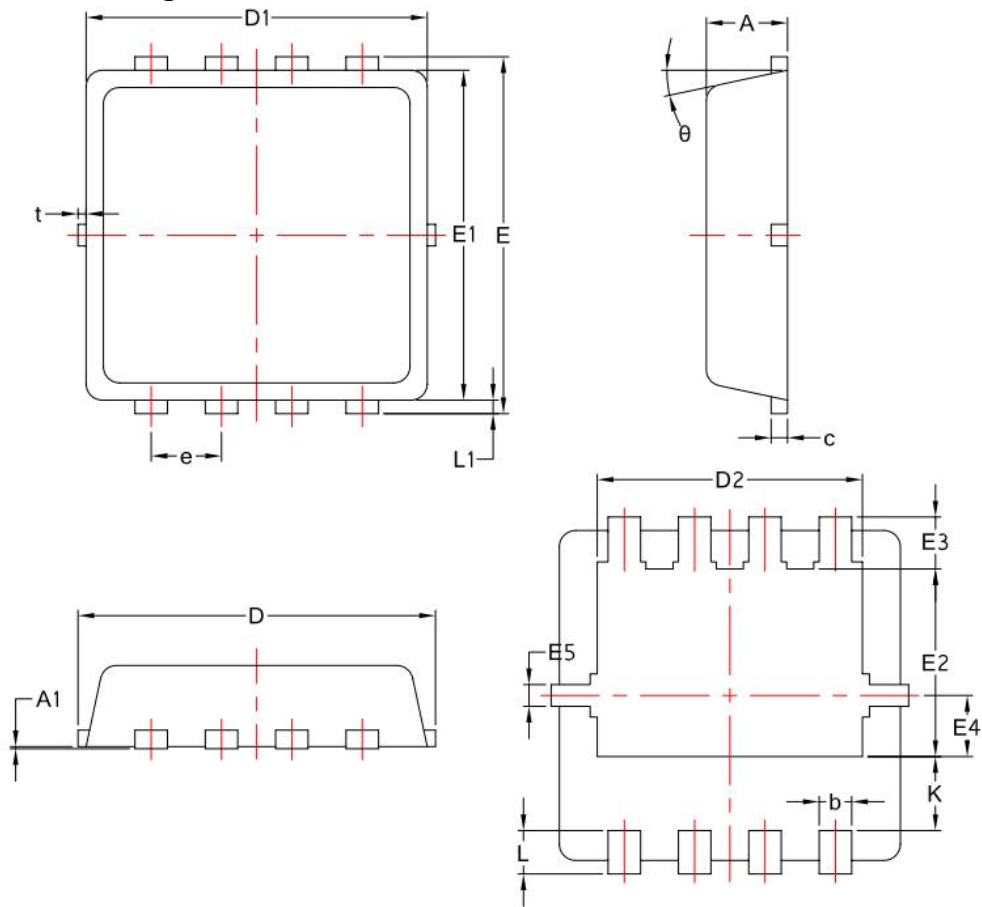


Figure 11 Normalized Maximum Transient Thermal Impedance

PDFN3.3X3.3-8L Package Information



SYMBOL	COMMON		
	MM		
	MIN	NOM	MAX
A	0.70	0.75	0.85
A1	/	/	0.05
b	0.20	0.30	0.40
c	0.10	0.152	0.25
D	3.15	3.30	3.45
$\triangle 2$ D1	3.00	3.15	3.25
$\triangle 2$ D2	2.29	2.45	2.65
E	3.15	3.30	3.45
E1	2.90	3.05	3.20
E2	1.54	1.74	1.94
$\triangle 3$ E3	0.28	0.48	0.65
E4	0.37	0.57	0.77
E5	0.10	0.20	0.30
e	0.60	0.65	0.70
$\triangle 2$ K	0.59	0.69	0.89
L	0.30	0.40	0.50
L1	0.06	0.125	0.20
$\triangle 2$ t	0	0.075	0.13
$\triangle 2$ θ	10°	12°	14°

Revision History

Revision	Date	Subjects
V1.0	2023.12.27	Product data sheet
V1.1	2024.04.29	Update $R_{DS(ON)}$ V_{TH} Typ Value

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